

Parameters Subject to Change Without Notice

DESCRIPTION

JW7707F is a synchronous rectifier for Flyback converters. It integrates a 50V power MOSFET that can replace Schottky diode for high efficiency. It turns on the internal MOSFET if the $V_{SW} < -500\text{mV}$ and turns it off before the current from GND to SW is lower than zero.

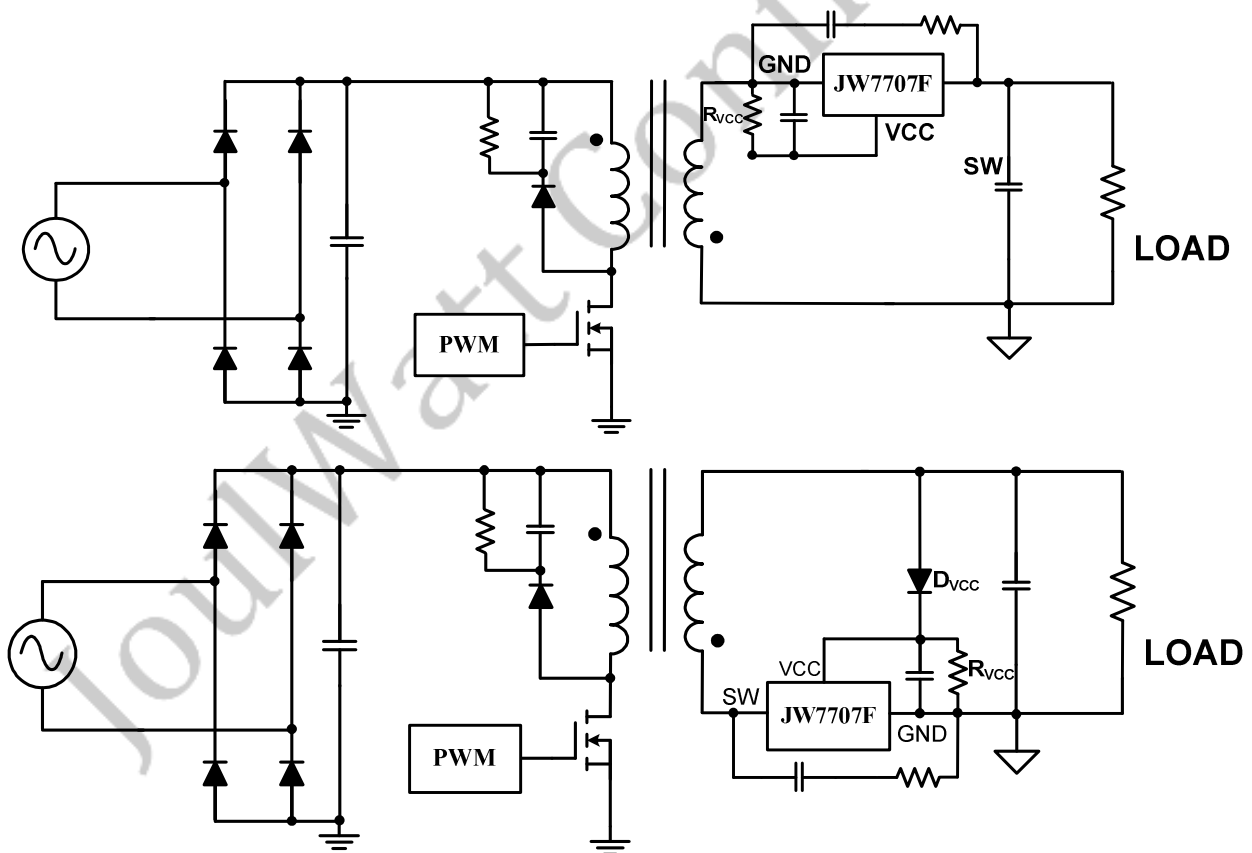
FEATURES

- Supports DCM and Quasi-Resonant Flyback converter
- Integrated 7mΩ 50V Power MOSFET
- Supports High-side and Low-side Rectification
- No need external power supply

APPLICATIONS

- Flyback converters
- Adaptors

TYPICAL APPLICATION



Note 1: R_{VCC} is recommended in case IC is damaged in CCM.

Note 2: D_{VCC} is recommended if VCC voltage is too low in light load.

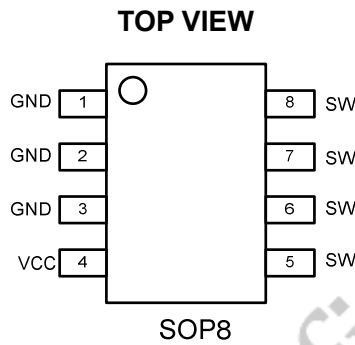
ORDER INFORMATION

LEAD FREE FINISH	TAPE AND REEL	PACKAGE	TOP MARKING
JW7707FSOPB#PBF	JW7707FSOPB#TRPBF	SOP8	JW7707F

Note:



PIN CONFIGURATION



ABSOLUTE MAXIMUM RATING¹⁾

SW PIN	55V
Maximum Power Dissipation ²⁾	2.5W
Junction Temperature ³⁾	150°C
Lead Temperature	260°C
Storage Temperature	-65°C to 150°C

RECOMMENDED OPERATING CONDITIONS

SW Pin	20V to 45V
VCC PIN	7V to 9V
Operation Junction Temp.	-40°C to 125°C

THERMAL PERFORMANCE⁴⁾

	θ_{JA}	θ_{Jc}
SOP8	96	45°C/W

Note:

- 1) Exceeding these ratings may damage the device.
- 2) $T_A=25^\circ\text{C}$. The maximum allowable power dissipation is a function of the maximum junction temperature $T_J(\text{MAX})$, the junction-to-ambient thermal resistance θ_{JA} , and the ambient temperature T_A . The maximum allowable continuous power dissipation at any ambient temperature is calculated by $P_D(\text{MAX})=(T_J(\text{MAX})-T_A)/\theta_{JA}$. Exceeding the maximum allowable power dissipation will cause excessive die temperature, and the regulator will go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.
- 3) Measured on JESD51-7, 4-layer PCB.

ELECTRICAL CHARACTERISTICS

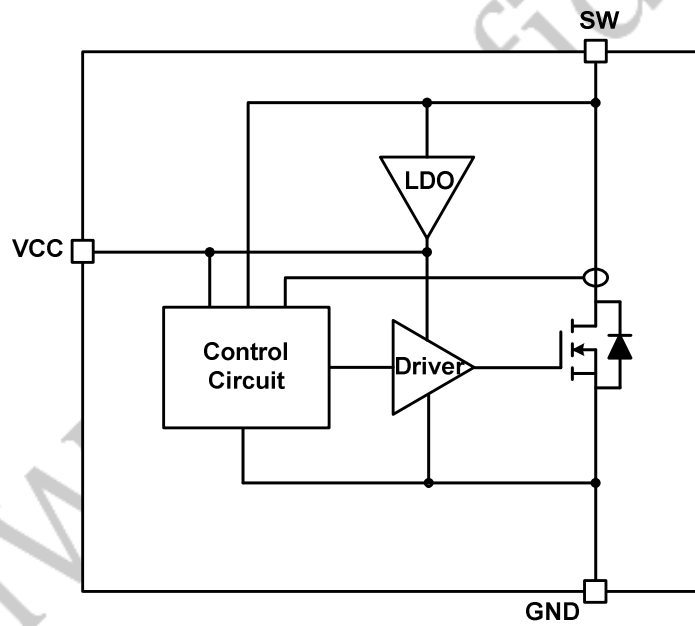
TA = 25°C, unless otherwise stated.

Item	Symbol	Condition	Min.	Typ.	Max.	Units
VCC Section						
VCC Operation Voltage	V_{CC}	SW=40V, VCC=0.1uF		7.8		V
VCC Start up Voltage	$V_{CC_STAR\ UP}$			3.85		V
VCC UVLO	V_{CC_UVLO}			3.6		V
Quiescent Current	I_Q	$V_{CC}=6.5V, C_{VCC}=0.1uF$	68	85	102	uA
Internal MOS Section						
Internal MOS R_{dson}	R_{dson}	VCC=8V, Isw=6A		7	10	mΩ
Maximum Peak Current	I_{peak}	$T_J=25^{\circ}C$		80		A
Drain Current-continuous	I_D	$T_J=25^{\circ}C$		50		A
Internal MOS turn on delay	T_{DON}			24		nS
Internal MOS turn off delay	T_{DOFF}			10		nS
Internal MOS turn on minimum time	T_{ON_MIN}			1		uS
Internal MOS turn off minimum time	T_{OFF_MIN}			2.5		uS
SW Section						
Internal MOS turn on Threshold	V_{MOS_ON}			-0.5		V
SW to GND Breakdown Voltage	$V_{(BR)DSS}$	VCC=9V, Isw=250uA	50			V

PIN DESCRIPTION

Pin No.	Name	Description
1、 2、 3	GND	Ground
4	VCC	Power supply, Bypass a capacitor between VCC and GND.
5、 6、 7、 8	SW	Internal Power MOSFET Drain.

BLOCK DIAGRAM



FUNCTIONAL DESCRIPTION

Operation

JW7707F is a synchronous rectifier, it can replace the Schottky to improve the efficiency in Flyback converters. It supports operation in DCM and Quasi-Resonant Flyback converters. It can power itself through the internal LDO during the turn-off period, a 0.1uF capacitor is needed between VCC and GND.

Turn-on Blanking Time

The control circuitry contains a blanking function. When the internal MOSFET is turned on, it at least last for some time, the turn on blanking time is about 500ns. During the turn on blanking period, the turn off threshold is not totally blanked, but changes the threshold current. This assures that the internal MOSFET can always be turned off even during the blanking period.

Under-Voltage Lockout (UVLO)

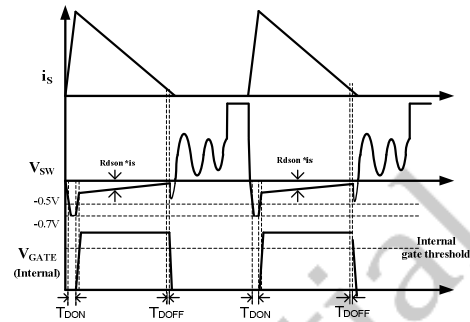
When the VCC is below UVLO threshold, the internal MOSFET is turned off and never turned on before the VCC exceeds the startup voltage.

Turn On Phase

The switch current first flows through the body diode of integrate MOSFET, which generates a negative V_{SW} . When the V_{SW} is higher than 0.7V and then V_{SW} is lower than V_{MOS_ON} , it turns on the integrate MOSFET after 100ns delay.

Turn Off Phase

The JW7707F senses the current of the internal MOSFET I_{SW} , before I_{SW} is lower than Internal MOS turn off threshold, the driver voltage of the switch is pulled down to zero after 10ns delay.



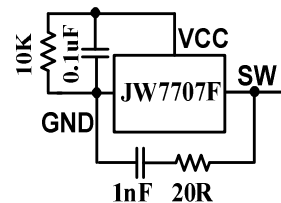
Turn on and turn off delay

Startup

During the startup period, when the VCC is lower than startup voltage, the internal MOSFET is turned off. The current flows through body diode until the VCC exceeds the startup voltage.

RC Snubber Circuit

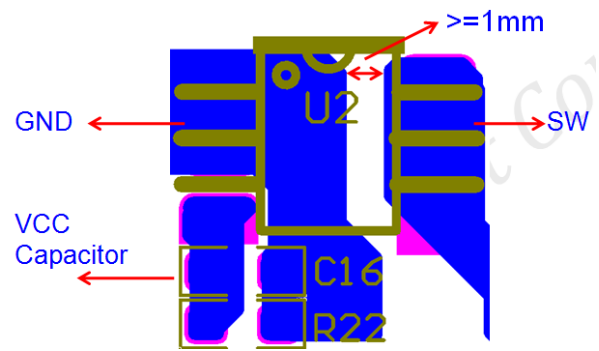
In some applications (output short circuit protection), the inductor current may go into slight CCM condition. To avoid the voltage spike across the synchronous rectifier, we suggest RC snubber should be placed between SW and GND, and a resistor should be paralleled with VCC capacitor.



RC Snubber circuit

PCB Layout Guidelines

1. The VCC pin must be locally bypassed with a capacitor.
2. The distance between GND and SW should be more than 1mm in case of too much coupled noise.
3. The EUT, a 5V/2A adaptor⁴⁾, can pass $\pm 25KV$ air discharging test by following with the recommended layout .



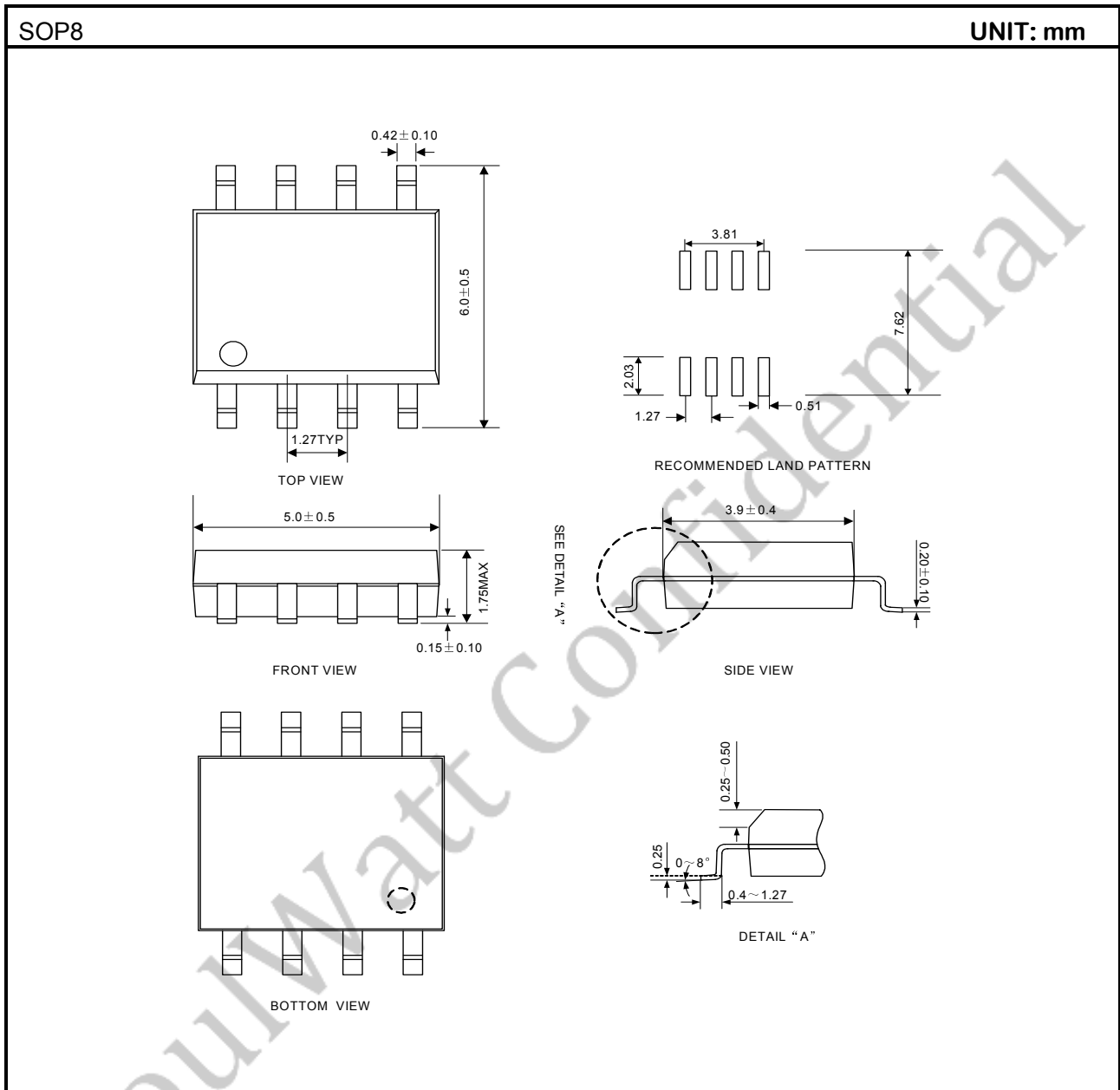
The recommended layout

Note:

- 4) ESD pass criterion is $\pm 15KV$ air discharging according to IEC61000-4-2. And the test equipment is TESEQ NSG 438.

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PACKAGE OUTLINE



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